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				Complete If Known			
	Substitute for	Form 1449A/PTO		Application Number	TBD		
	INFORMATIO	N DISCLOSURE		Filing Date	Herewith		
	-			First Named Inventor	Srinivasan Chakravarthi, et al.		
STATEMENT BY APPLICANT				Group Art Unit	2813		
	(use as many sl	neets as necessary)		Examiner Name	Yennhu B. Huyh		
Sheet	1	of	11	Attomey Docket No.	TI-33161.1		

				U.S. I	PATENT DOCUME	ENTS		
	Cite No.1	U.S. Patent Document		Name of Patentee	Date of Pub.			
Exam. Initials*		Number	Kind Code ² (if known)	or Applicant of Cited Doc.	of Cited Doc. (mm-dd-yyyy)	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear		
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		Foreign Patent Document			Name of Patentee	Date of Pub.		
Exam. Initials*	Cite No. ¹	Office ³	Number ⁴	Kind Code ² (if known)	or Applicant of Cited Doc.	of Cited Doc. (mm-dd-yyyy)	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	
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		OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS	
Exam. Initials*	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
PD	CA	P. PACKAN ET AL., "Modeling Solid Source Boron Diffusion for Advanced Transistor Applications" IEEE, IEDM 98, pp. 505-508	
PD	СВ	DANIEL F. DOWNEY ET AL., "Effect of Fluorine on the Diffusion of Boron in Ion Implanted Si" 1998 American Institute of Physics, Vol. 73, Number 9, August 31, 1998, pp. 1263-1265	
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Signature Considered Considered	Examiner Signature	PHOC T. DANG	Date Considered 2	128/04
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